

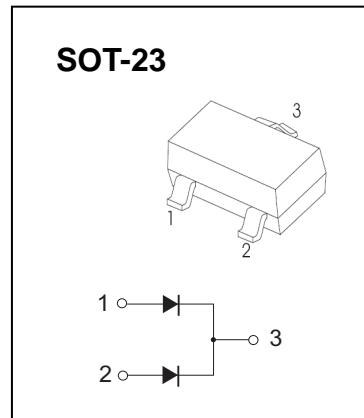


JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-23 Plastic-Encapsulate Diodes

MC2838 SWITCHING DIODE**FEATURES**

- High speed switching
- Low capacitance

MARKING:A61**Maximum Ratings @Ta=25°C**

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	75	V
DC Blocking Voltage	V _R	50	V
Average Rectified Output Current	I _O	100	mA
Power Dissipation	P _D	150	mW
Junction Temperature	T _J	150	°C
Storage Temperature Range	T _{STG}	-55 ~+150	°C

Electrical Characteristics @Ta=25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward voltage	V _{F1}	I _F =10mA		0.67	0.9	V
	V _{F2}	I _F =50mA		0.75	1.0	V
	V _{F3}	I _F =100mA		0.85	1.2	V
	I _R	V _R =50V			0.1	uA
Reverse recovery time	t _{rr}	I _F =10mA, V _R =6V, R _L =100Ω I _r =0.1*I _R			3.0	ns
Capacitance between terminals	C _T	V _R =0, f=1MHz		1.1	4.0	pF

Typical Characteristics

MC2838

